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(71) Applicant (for all designated States except US): GEN-  
ERAL ELECTRIC COMPANY [US/US]; 1 River Road,  
Schenectady, NY 12345 (US).

(72) Inventors; and

(75) Inventors/Applicants (for US only): GUI, John, Yupeng  
[US/US]; 10 Oaktree Lane, Niskayuna, NY 12309 (US).  
KHOURI, Farid, Fouad [US/US]; 6 Tamarack Lane,  
Clifton Park, NY 12065 (US). JOHNSON, Norman,  
Enoch [US/US]; 1251 Tanglewood Drive, Mount Ver-  
non, IN 47620 (US). GUGGENHEIM, Thomas, Link  
[US/US]; 7160 Upton Road, Mount Vernon, IN 47620  
(US). WOODRUFF, David, Winfield [US/US]; 12 Sey-  
mour Drive, Saratoga Springs, NY 12866 (US). SILVA,  
James, Manio [US/US]; 20 Nottingham Way North,  
Clifton Park, NY 12065 (US).

(74) Agents: WINTER, Catherine, J. et al.; Patent Counsel,  
General Electric Company, 3135 Easton Turnpike (W3C),  
Fairfield, CT 06828 (US).

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ning of each regular issue of the PCT Gazette.

(54) Title: METHOD TO PREPARE BIS(HALOPHTHALIMIDES)

(57) Abstract: Bis(halophthalimides) are prepared in mixture in an organic liquid such as orthodichlorobenzene or anisole, by a reaction at a temperature of at least 150°C between at least one diamine compound and at least one halophthalic anhydride in the presence of imidization catalyst. The reaction mixture is maintained at about 15% by weight solids content and rich in the halophthalic anhydride by constantly monitoring the reaction mixture using analytical methods such as high performance liquid chromatography. The product mixture may be directly employed in the direct preparation of polyetherimides, and similar slurries may be employed to prepare other polyether polymers.

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